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Sec: 12

Quiz: 4

Circuit Parameters:

$$K_n' = 200 \mu A/V^2 = 0.2 mA/V$$

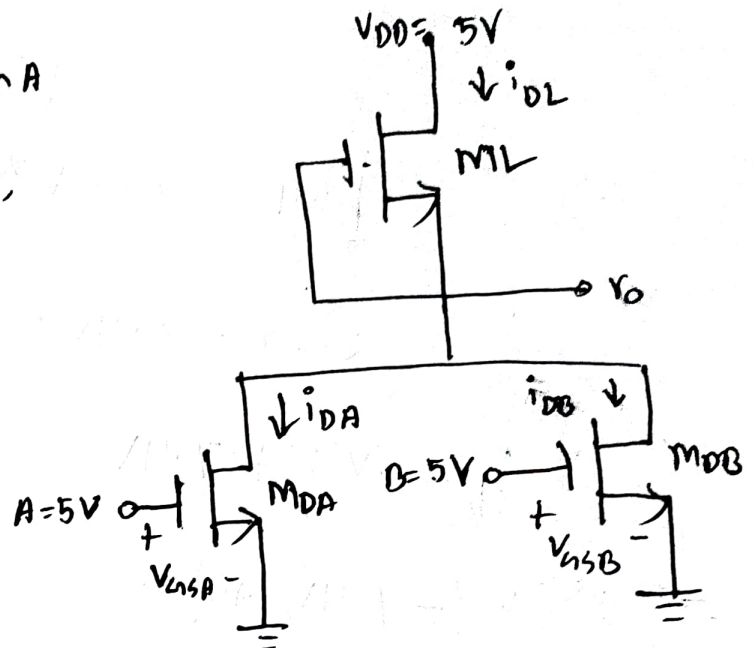
$$V_{TNL} = -0.5V, V_{TNA} = 1V,$$

$$V_{TNB} = 1.5V$$

$$\left(\frac{W}{L}\right)_L = 1$$

$$\left(\frac{W}{L}\right)_A = 2$$

$$\left(\frac{W}{L}\right)_B = 3$$



- (a) As, this is a nand gate, when two inputs are high, output will a low voltage. So, V_o is small.

Hence,

$$V_{GS_L} = V_{GL} - V_{SL} = 0V$$

$$V_{DS_L} = V_{DL} - V_{SL}$$

$$= 5 - V_o \text{ [large value]}$$

$$V_{DS_L} \geq V_{GS_L} - V_{TNL} = 0 - (-0.5) = 0.5$$

$$\Rightarrow 5 - V_o \geq 0.5$$

So, M_L in saturation mode.

Assuming

M_{DA}, M_{DB} in triode mode.

$$i_{DL} = i_{DA} + i_{DB}$$

$$\Rightarrow k_n' \left(\frac{W}{L}\right)_L (0.5)^2 = k_n' \left(\frac{W}{L}\right)_A (2(5-1)V_0 - V_0^2) + k_n' \left(\frac{W}{L}\right)_B (2(5-1.5)V_0 - V_0^2)$$

$$\Rightarrow \frac{1}{20} = [0.4 \times (8V_0 - V_0^2)] + [0.6 \times (7V_0 - V_0^2)]$$

$$\Rightarrow \frac{1}{20} = 3.2V_0 - 0.4V_0^2 + 4.2V_0 - 0.6V_0^2$$

$$\Rightarrow \frac{1}{20} = -V_0^2 + 7.4V_0$$

$$\Rightarrow V_0^2 - 7.4V_0 + \frac{1}{20} = 0$$

$$\Rightarrow V_0 = \begin{cases} 7.393 \\ 6.763 \times 10^{-3} \end{cases} \quad [\text{Not valid}]$$

$$\text{So, } \boxed{V_0 = 6.763 \times 10^{-3} \text{ V}} \quad (\text{Ans})$$

(b)

As,

this is a nMOS gate, and inputs are high, the output voltage will be low.

Therefore

$$V_{GS} = V_{GS} - V_{SL} = 0V$$

$$V_{DS} = V_{DL} - V_{SL}$$

$$= 5 - V_0 \text{ [large value]}$$

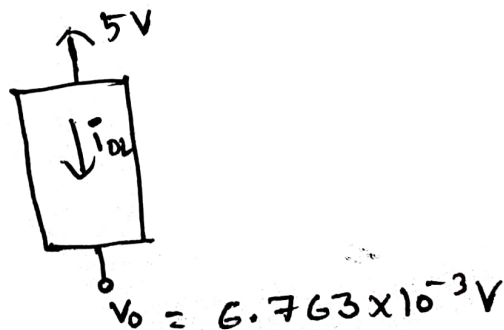
Thus,

$$V_{DS} > V_{GS} - V_{TNL} = 0.5$$

$$\Rightarrow 5 - V_0 > 0.5$$

For this, M_L must be in saturation mode.

Power dissipation of load transistor:



$$\text{So, } P = \Delta V \times I_{DL}$$

$$I_{DL} = \frac{1}{20} = 0.05 \text{ mA}$$

$$\text{So, } P = (5 - 6.763 \times 10^3) \times 0.05$$

$$= \boxed{0.2497 \text{ mW}} \quad \text{Power dissipation of load transistor}$$

(Ans)

